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July 2015

FDMS86500DC

N-Channel Dual CoolTM 56 Power Trench[®] MOSFET 60 V, 108 A, 2.3 m Ω

Features

- Dual CoolTM Top Side Cooling PQFN package
- Max $r_{DS(on)}$ = 2.3 m Ω at V_{GS} = 10 V, I_D = 29 A
- Max $r_{DS(on)} = 3.3 \text{ m}\Omega$ at $V_{GS} = 8 \text{ V}$, $I_D = 24 \text{ A}$
- High performance technology for extremely low r_{DS(on)}
- 100% UIL Tested
- RoHS Compliant

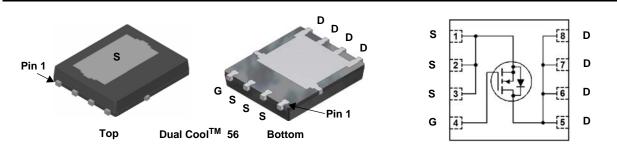


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench[®] process. Advancements in both silicon and Dual CoolTM package technologies have been combined to offer the lowest $r_{DS(on)}$ while maintaining excellent switching performance by extremely low Junction-to-Ambient thermal resistance.

Applications

- Synchronous Rectifier for DC/DC Converters
- Telecom Secondary Side Rectification
- High End Server/Workstation Vcore Low Side



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Param	neter		Ratings	Units
V _{DS}	Drain to Source Voltage			60	V
V _{GS}	Gate to Source Voltage			±20	V
	Drain Current -Continuous	T _C = 25 °C		108	
I _D	-Continuous	T _A = 25 °C	(Note 1a)	29	Α
	-Pulsed			200	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	317	mJ
D	Power Dissipation	T _C = 25 °C		125	W
PD	Power Dissipation	T _A = 25 °C	(Note 1a)	3.2	vv
T _J , T _{STG}	Operating and Storage Junction Temper	ature Range		-55 to +150	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Top Source)	2.8	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case	(Bottom Drain)	1.0	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	38	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1b)	81	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1i)	16	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1j)	23	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1k)	11	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
86500	FDMS86500DC	Dual Cool [™] 56	13"	12 mm	3000 units

FDMS86500DC N-Channel Dual Cool
Cool TM
6
56 Power T
Trench [®]
MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	icteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, \ V_{GS} = 0 \ V$	60			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25°C		30		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 48 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	2.5	3.7	4.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-12		mV/°C
	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 29 A		1.9	2.3	
r _{DS(on)}		V _{GS} = 8 V, I _D = 24 A		2.4	3.3	mΩ
		$V_{GS} = 10 \text{ V}, \ \text{I}_{D} = 29 \text{ A}, \ \text{T}_{J} = 125 \ ^{\circ}\text{C}$		3.0	3.7	
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 29 A		98		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			5775	7680	pF
C _{oss}	Output Capacitance	V _{DS} = 30 V, V _{GS} = 0 V, f = 1 MHz		1605	2680	pF
C _{rss}	Reverse Transfer Capacitance			48	95	pF
R _g	Gate Resistance		0.1	1	3	Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			35	56	ns
t _r	Rise Time	V _{DD} = 30 V , I _D = 29 A,		25	40	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		34	54	ns
t _f	Fall Time	-		8.2	17	ns
	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		76	107	nC
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 \text{ V to } 8 \text{ V}$ $V_{DD} = 30 \text{ V}$		62	87	nC
Q _{gs}	Total Gate Charge	I _D = 29 A		31		nC
Q _{gd}	Gate to Drain "Miller" Charge			15		nC

M	V	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.7 A$ (Note 2)	0.71	1.2	V
	V _{SD}	Source to Drain Diode Porward Voltage	$V_{GS} = 0 V, I_S = 29 A$ (Note 2)	0.79	1.3	v
	t _{rr}	Reverse Recovery Time	I⊨ = 29 A. di/dt = 100 A/μs	59	95	ns
	Q _{rr}	Reverse Recovery Charge	$F = 25 A$, $u/ut = 100 A/\mu s$	46	74	nC

b. 81 °C/W when mounted on

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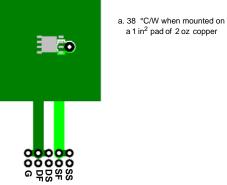
a minimum pad of 2 oz copper

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Top Source)	2.8	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Bottom Drain)	1.0	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	38	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	81	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1c)	27	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1d)	34	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1e)	16	0000
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1f)	19	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1g)	26	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1h)	61	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1i)	16	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1j)	23	
R _{0JA}	Thermal Resistance, Junction to Ambient	(Note 1k)	11	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1I)	13	

NOTES:

1. R_{0,A} is determined with the device mounted on a FR-4 board using a specified pad of 2 oz copper as shown below. R_{0,JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



c. Still air, 20.9x10.4x12.7mm Aluminum Heat Sink, 1 in 2 pad of 2 oz copper

d. Still air, 20.9x10.4x12.7mm Aluminum Heat Sink, minimum pad of 2 oz copper

e. Still air, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, 1 in² pad of 2 oz copper

f. Still air, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, minimum pad of 2 oz copper

g. 200FPM Airflow, No Heat Sink,1 in² pad of 2 oz copper

h. 200FPM Airflow, No Heat Sink, minimum pad of 2 oz copper

i. 200FPM Airflow, 20.9x10.4x12.7mm Aluminum Heat Sink, 1 in 2 pad of 2 oz copper

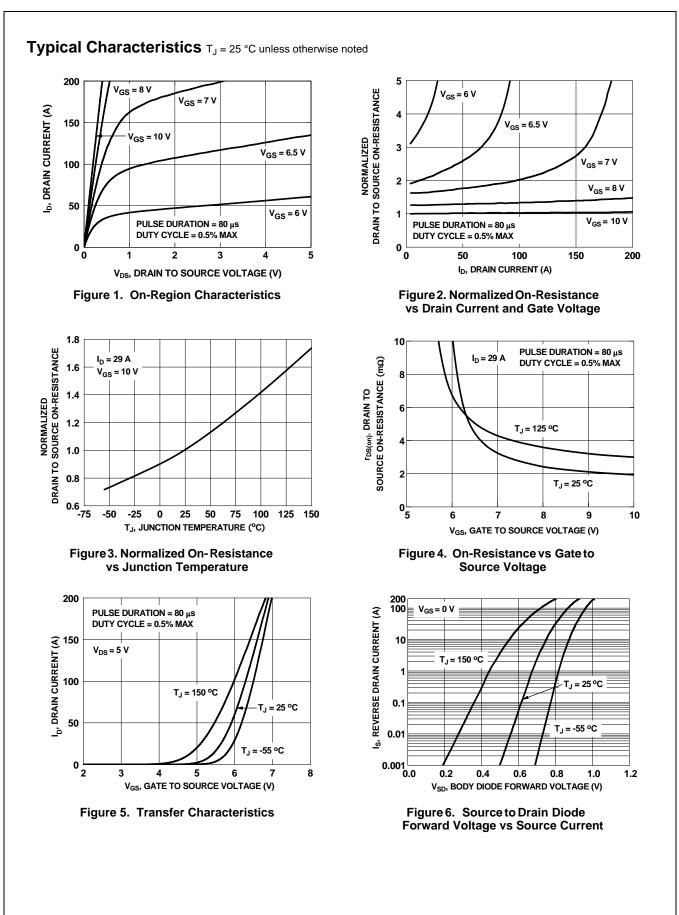
j. 200FPM Airflow, 20.9x10.4x12.7mm Aluminum Heat Sink, minimum pad of 2 oz copper

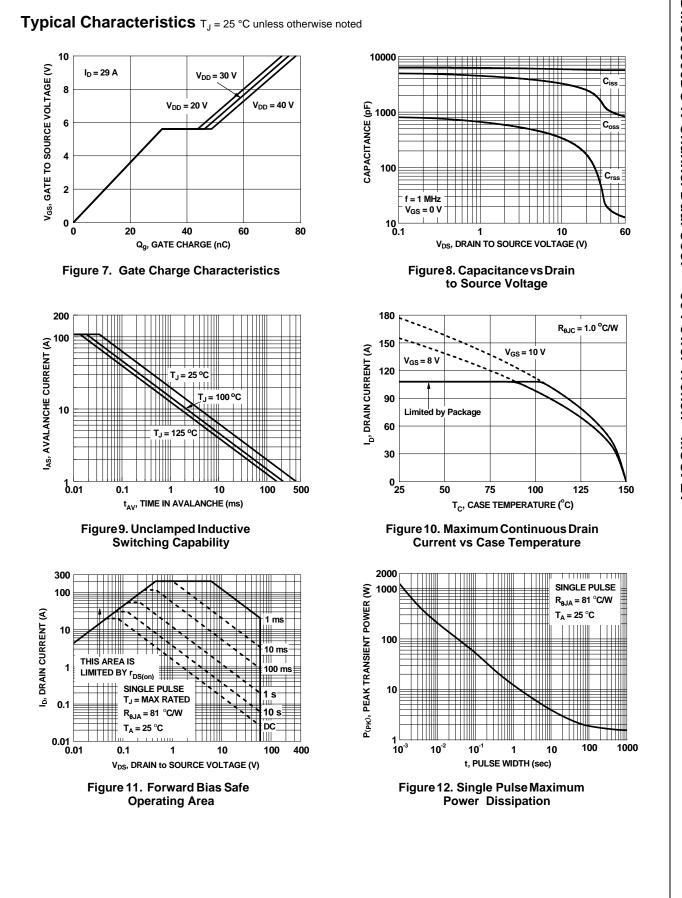
k. 200FPM Airflow, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, 1 in² pad of 2 oz copper

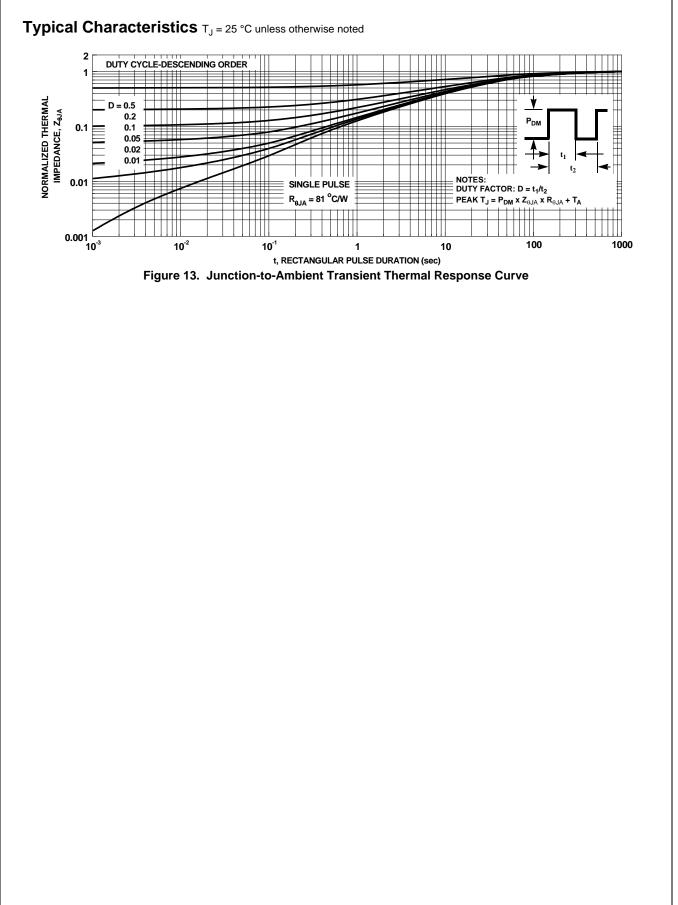
I. 200FPM Airflow, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, minimum pad of 2 oz copper

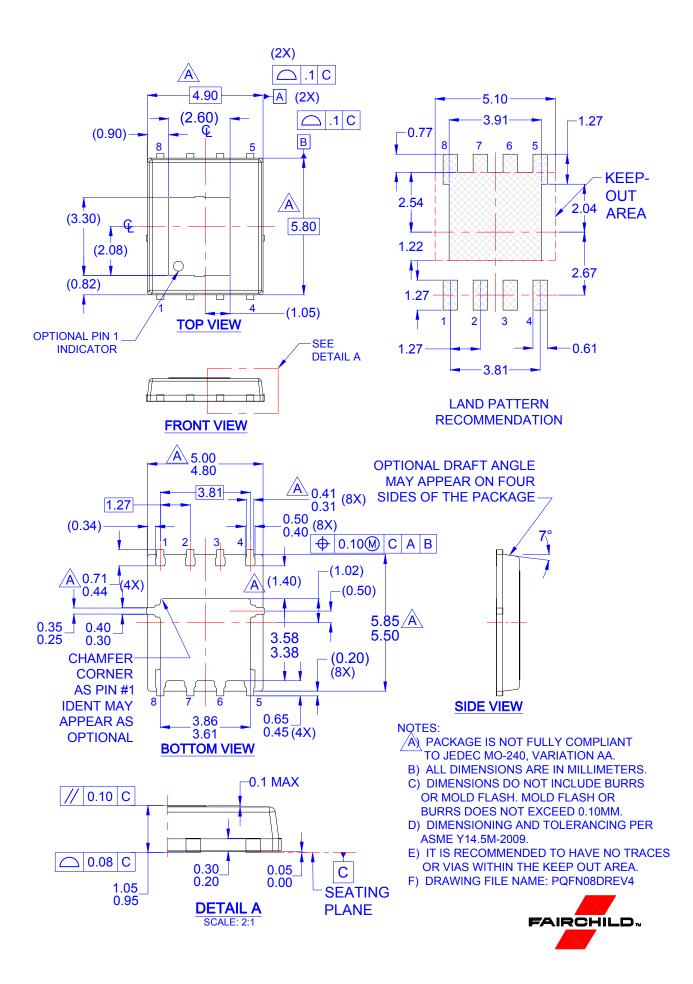
2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%.

3. Starting T_J = 25 °C; N-ch: L = 0.3 mH, I_{AS} = 46 A, V_{DD} = 54 V, V_{GS} = 10 V.









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